

# Photon-number resolution with Transition-Edge Sensors

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(1)



(2)



Politecnico  
di Torino

**ScuDo**  
Scuola di Dottorato ~ Doctoral School  
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# Our group at INRiM

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Italy's National Metrology Institute in Turin



Innovative Cryogenic Detectors Laboratory

**Mauro Rajteri**



Researcher

**Eugenio Monticone**



Researcher

**Hobey Garrone**



PhD student

**Federico Malnati**

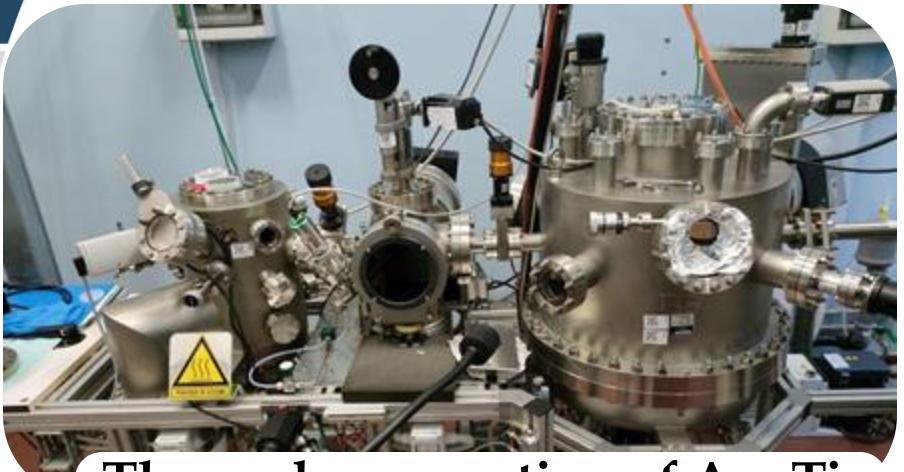


PhD student

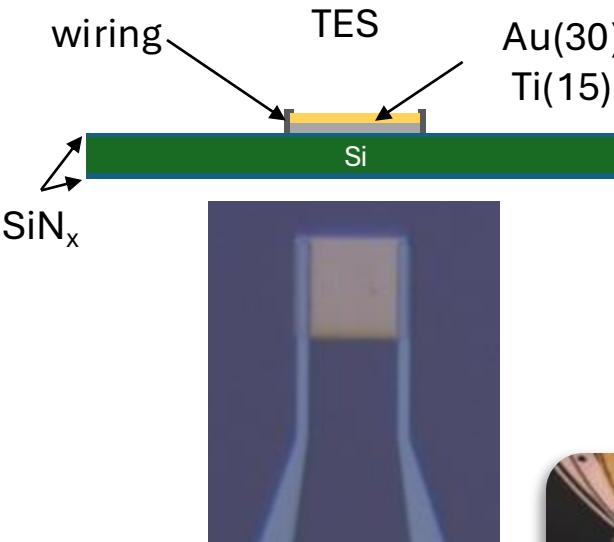
# INRiM facilities for TESs

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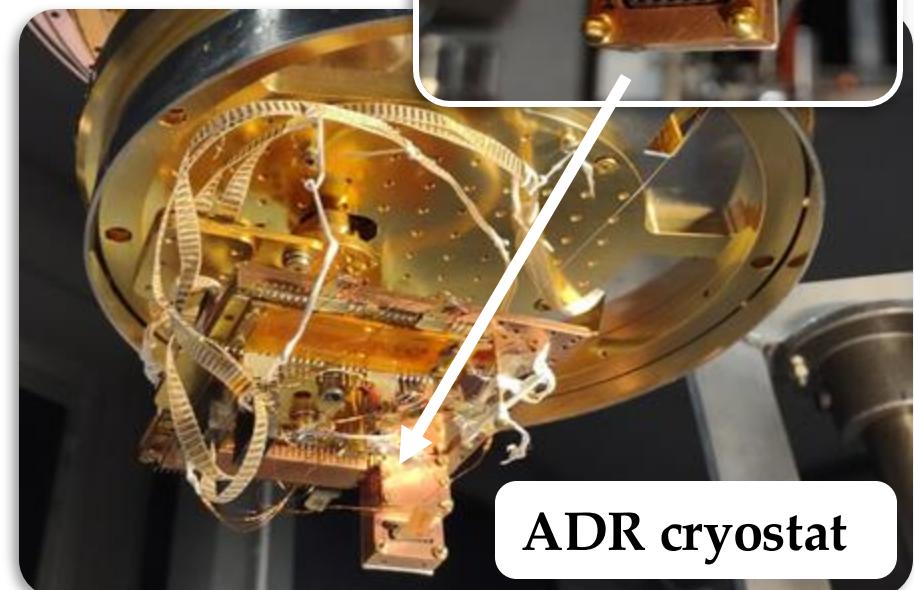
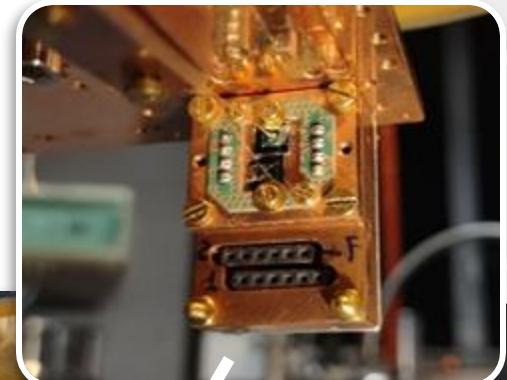
## Fabrication



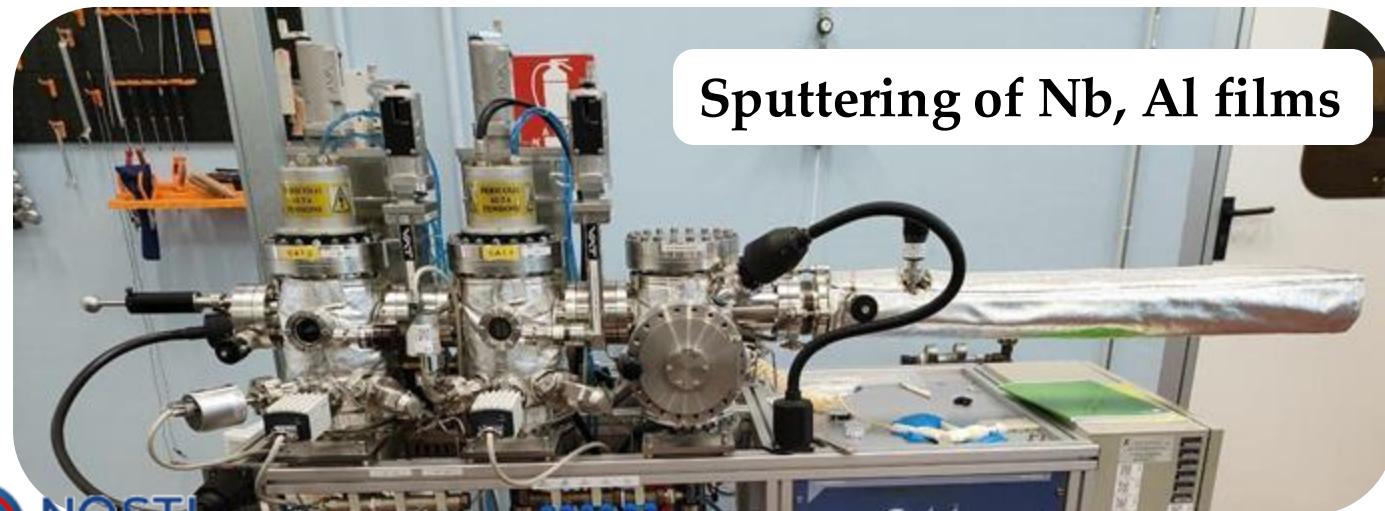
Thermal evaporation of Au ,Ti.  
Depositions in rapid sequence.



## Characterization



ADR cryostat



Sputtering of Nb, Al films

Array of single photon detectors based on:  
superconducting transition-edge sensors (TESs)



## Requirements:

- Resolving power of 4 (for precise photon-number discrimination)
- Response time  $< 1 \mu\text{s}$
- Detection quantum efficiency  $> 90\%$



## Technology:

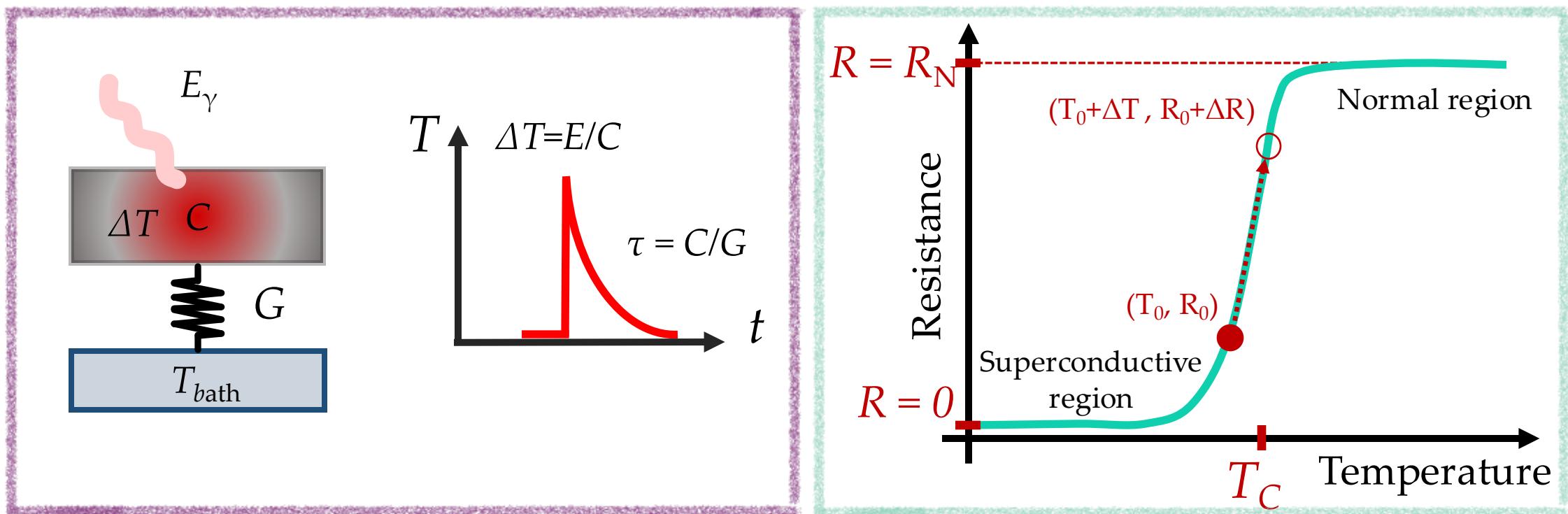
- Tuning TESs critical temperature using **proximity effect**
- **Antireflection coating** and **optical cavity** for maximizing QE



# Transition-Edge Sensors

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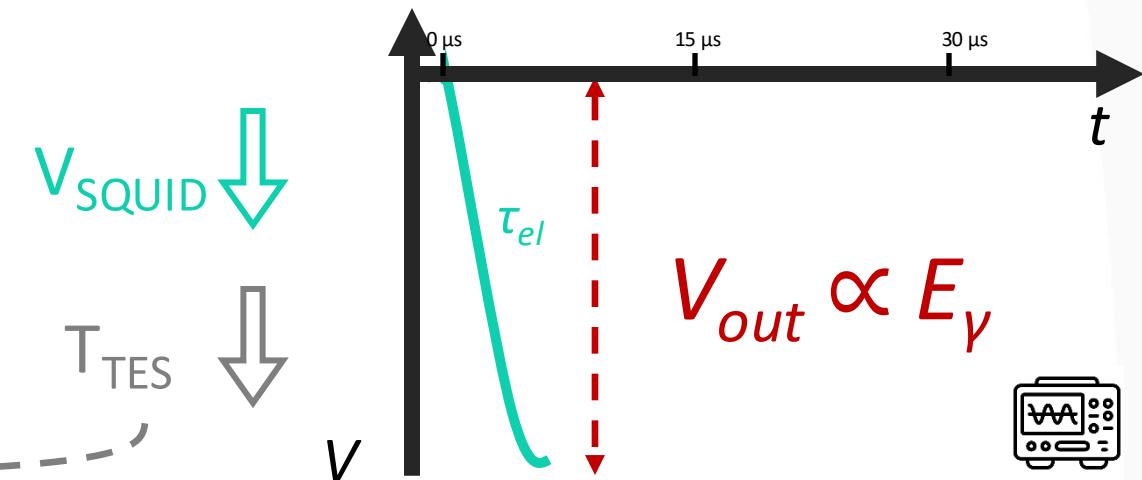
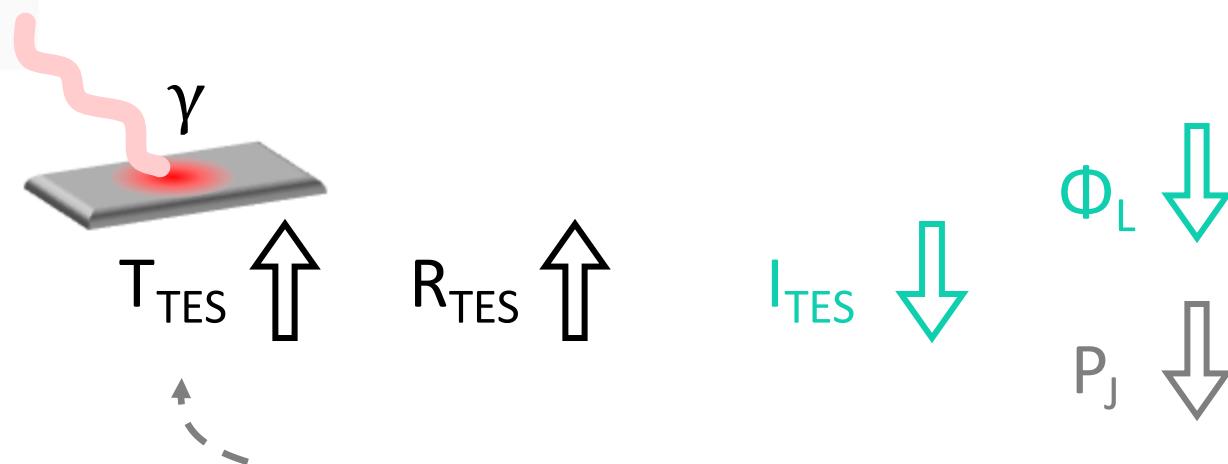
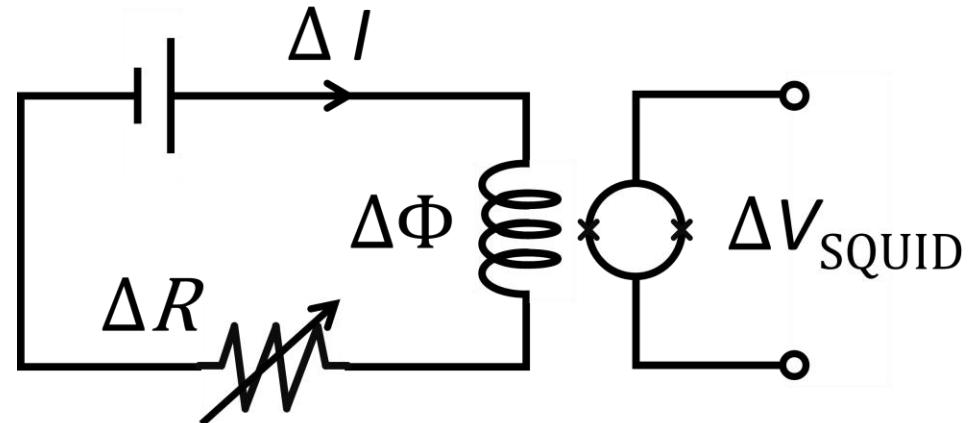
- TES: detector that exploit the strongly **temperature-dependent resistance** of the superconducting phase transition occurring at critical temperature  $T_c$



# TES working principle

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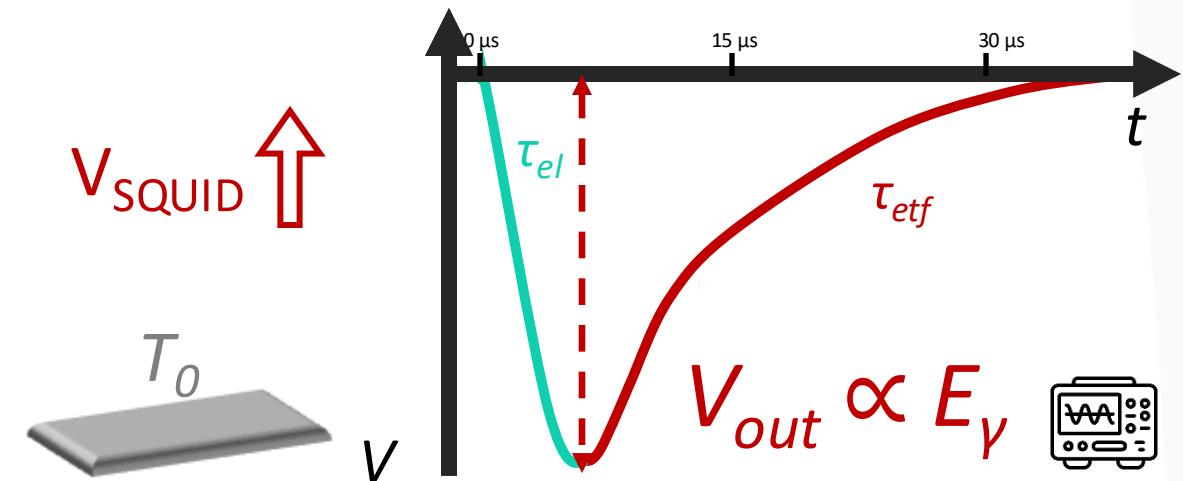
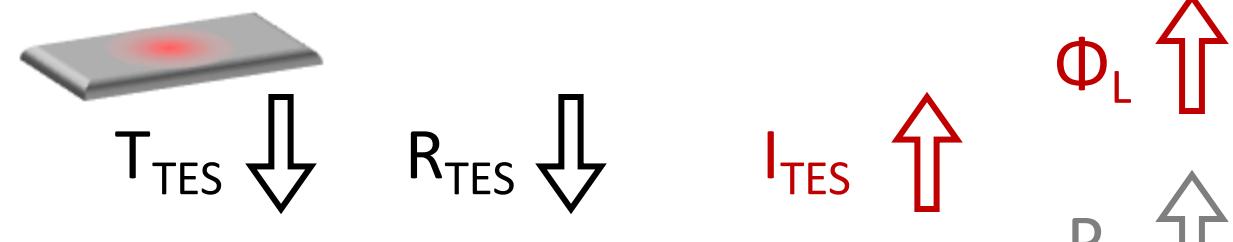
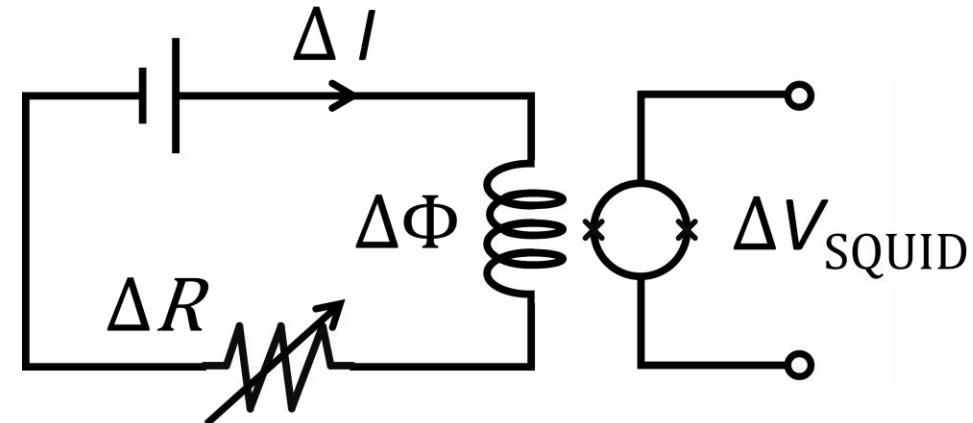
Electrothermal Feedback (Irwin, 1995)



# TES working principle

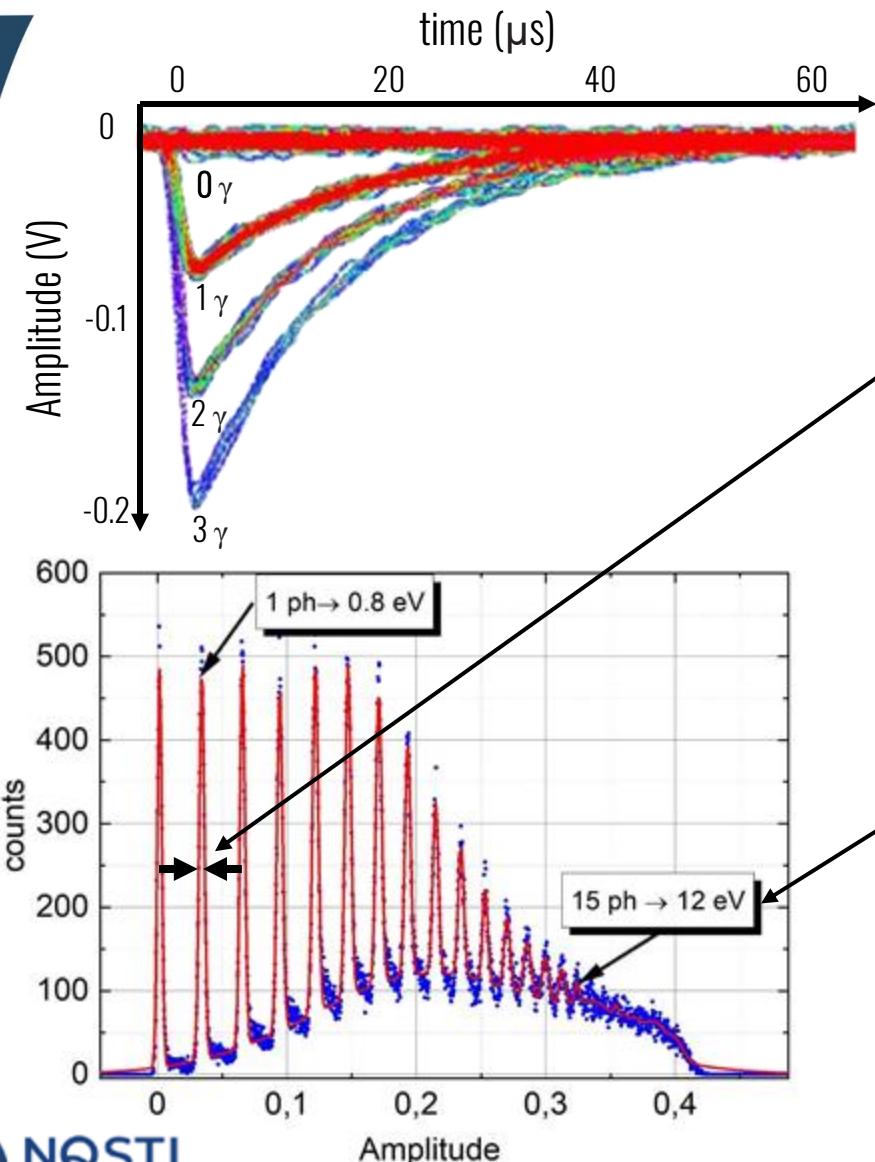
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Electrothermal Feedback (Irwin, 1995)



# Some Figures of Merit

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**Energy resolution:**

$$\Delta E_{FWHM} \simeq 7 \sqrt{k_B E_{sat} T_c \sqrt{(1 + 2\beta)(1 + M^2)}} \\ \propto \sqrt{k^{-1} A T_c^3} \quad \simeq 10$$

**Saturation energy:**

$$E_{sat} \simeq \frac{CT_c}{\alpha} \propto A T_c^2$$

Best result @INRIM  $\Leftrightarrow \Delta E = 0.11 \text{ eV}$  @NIR  
 $(20 \times 20) \mu\text{m}^2$

# Recent developments: fast TESs

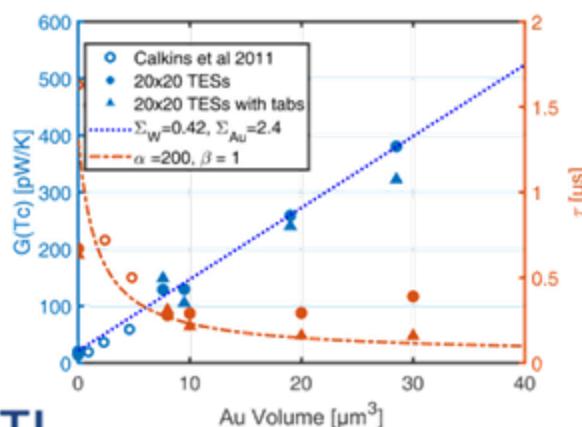
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$$\text{Recovery time} \propto \frac{C_e}{G} \propto T_c^{-3}$$

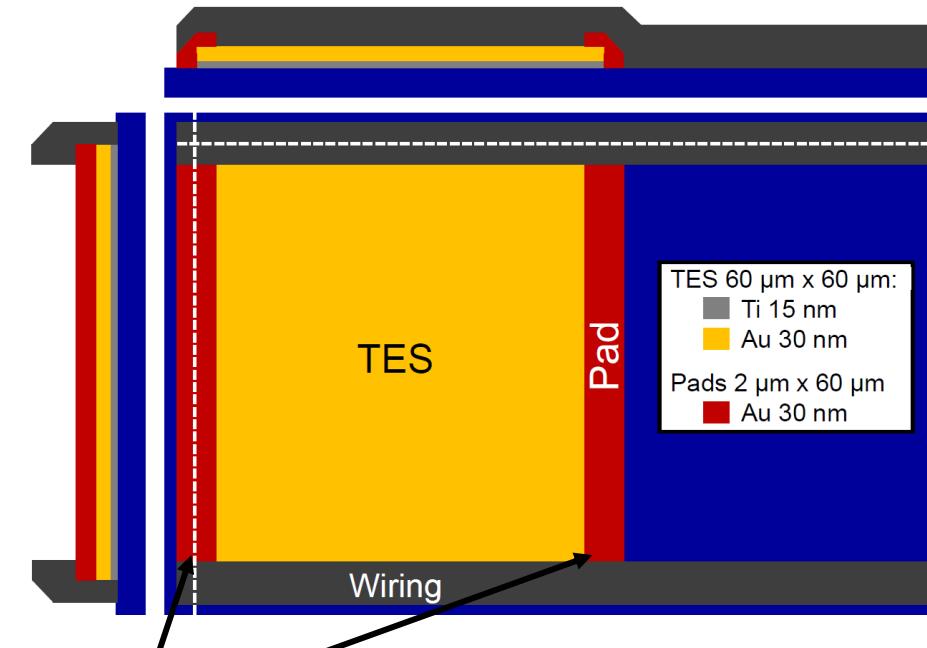
( $\sim 5\tau_{\text{etf}}$ )



Enhance the thermal conductance by adding Au pads in TES design



[5] Hummatov, "Fast transition-edge sensors suitable for photonic quantum computing". Journal of Applied Physics (2023).



Au pads on  
two sides

Wiring deposited  
on the other sides

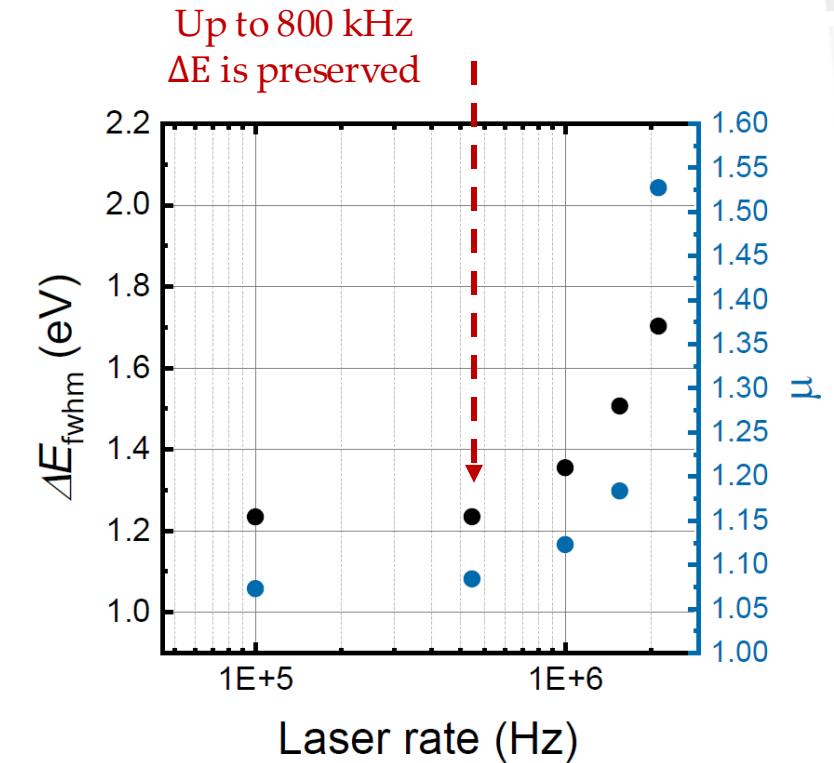
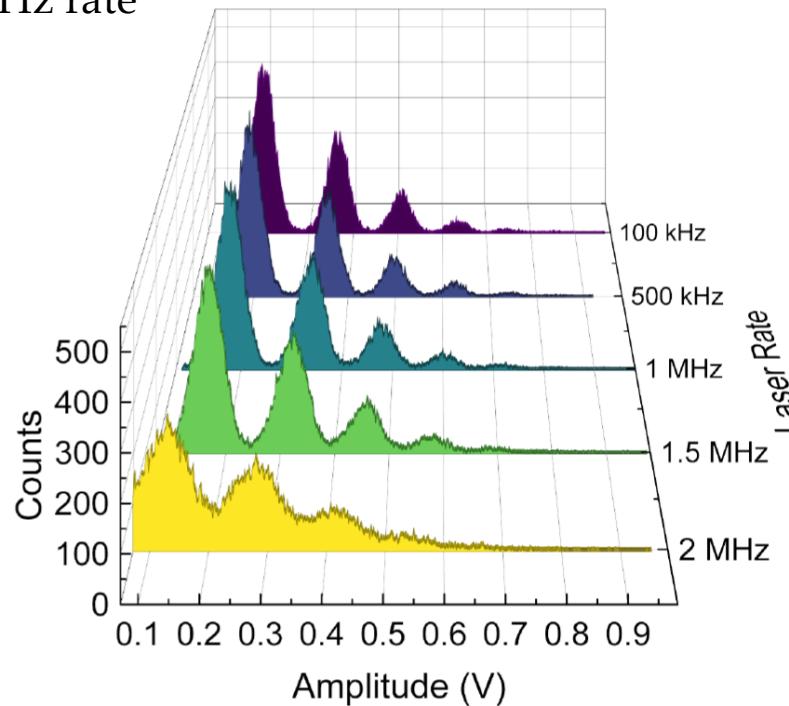
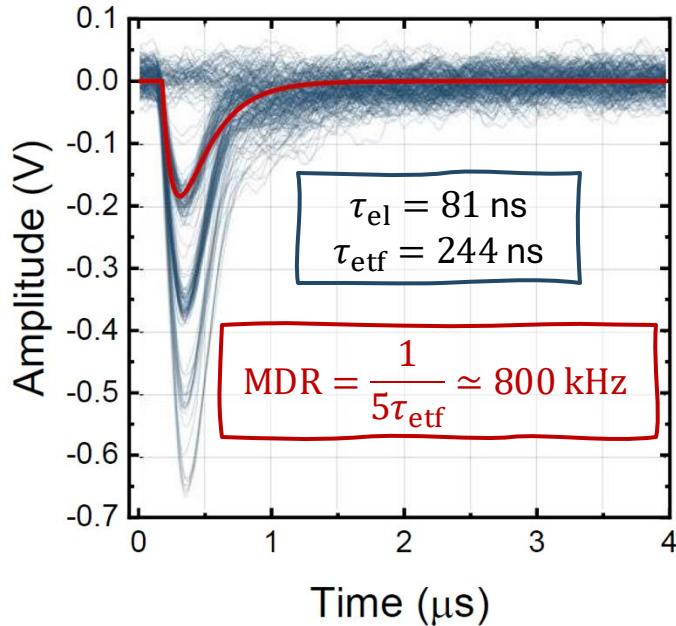
# Speeding up TESs

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TiAu TES with a  $T_C = 123$  mK and **two** gold pads

$$G = 654 \pm 5 \text{ pW/K}$$

TES response to 406 nm photons @50 kHz rate



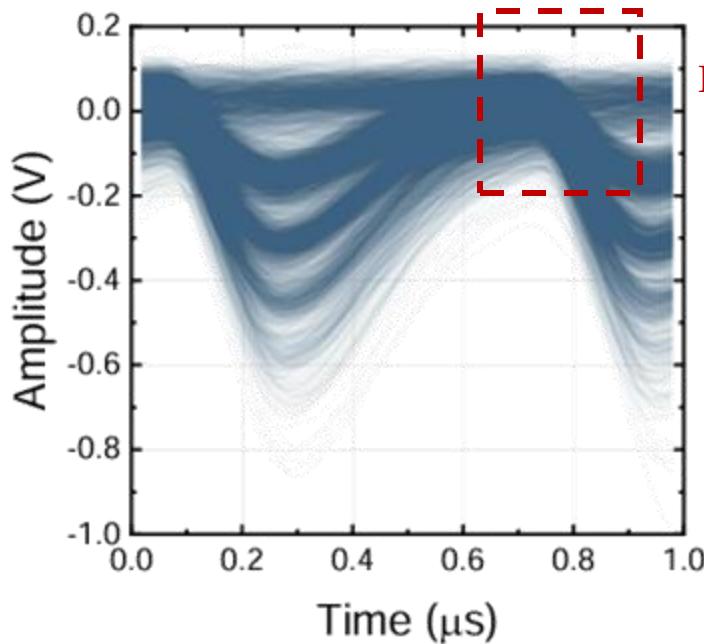
# Speeding up TESs

11

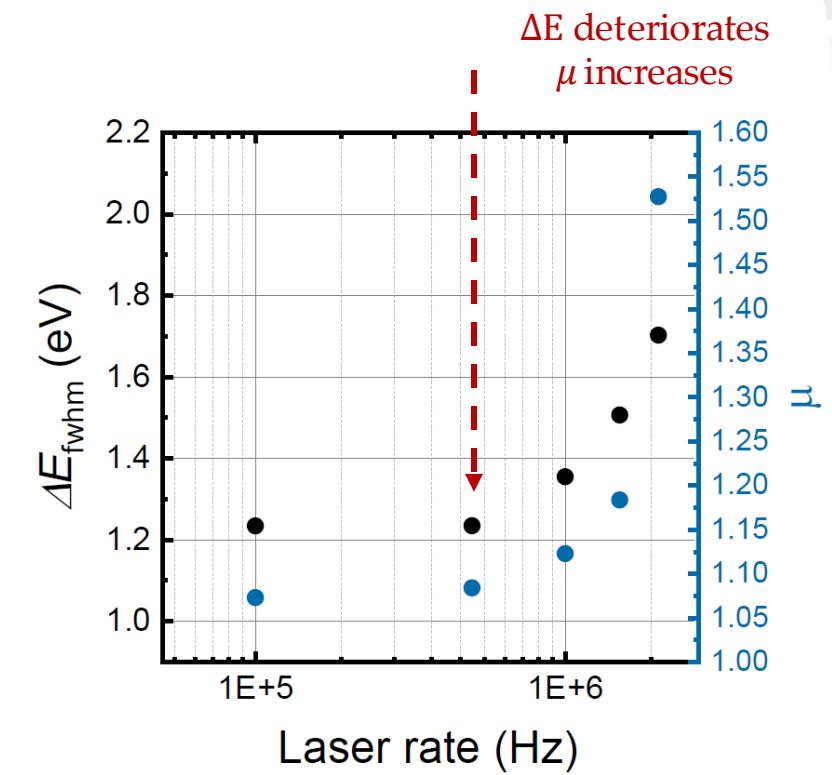
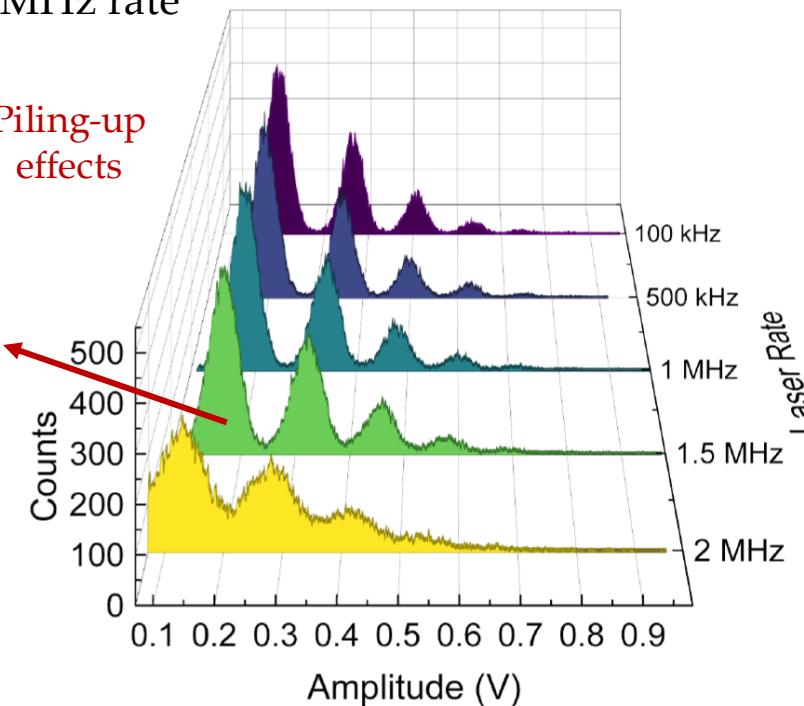
TiAu TES with a  $T_C=123$  mK and **two** gold pads

$$G = 654 \pm 5 \text{ pW/K}$$

TES response to 406 nm photons @1.5 MHz rate



Piling-up effects



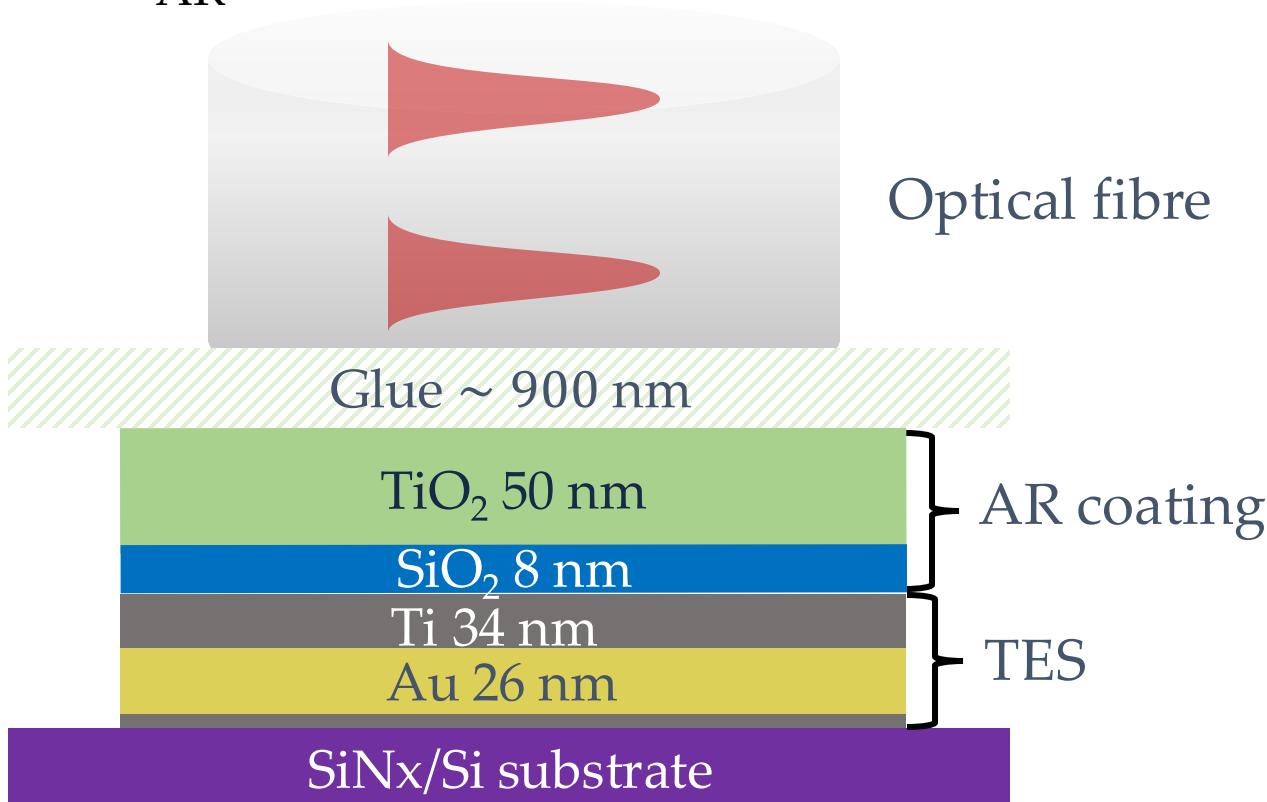
TiAu TES with **one** gold pad  $\rightarrow G = 413 \pm 5 \text{ pW/K}$  (-37%) and MDR  $\simeq 470 \text{ kHz}$

# High efficiency TES layout

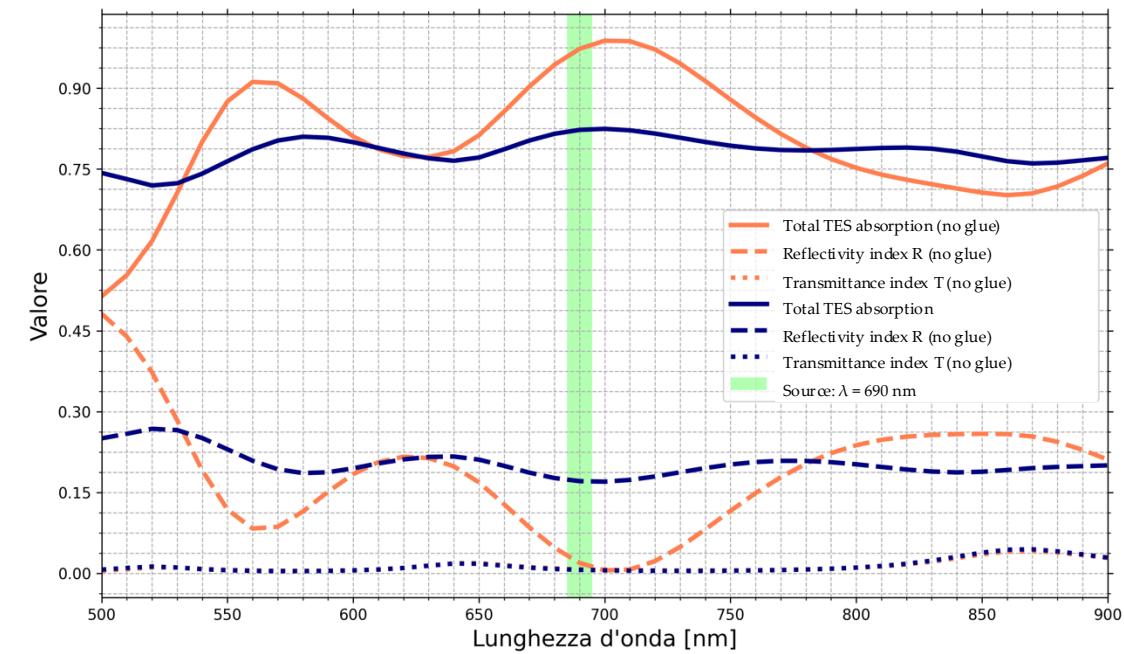
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- Enhancing TES detection efficiency

$12 \times 12 \mu\text{m}^2$  and  $60 \times 60 \mu\text{m}^2$  TiAuTi TESs + AR



Maximum of absorption around  $\lambda = 700 \text{ nm}$



Laser source  $\lambda = 690 \text{ nm}$

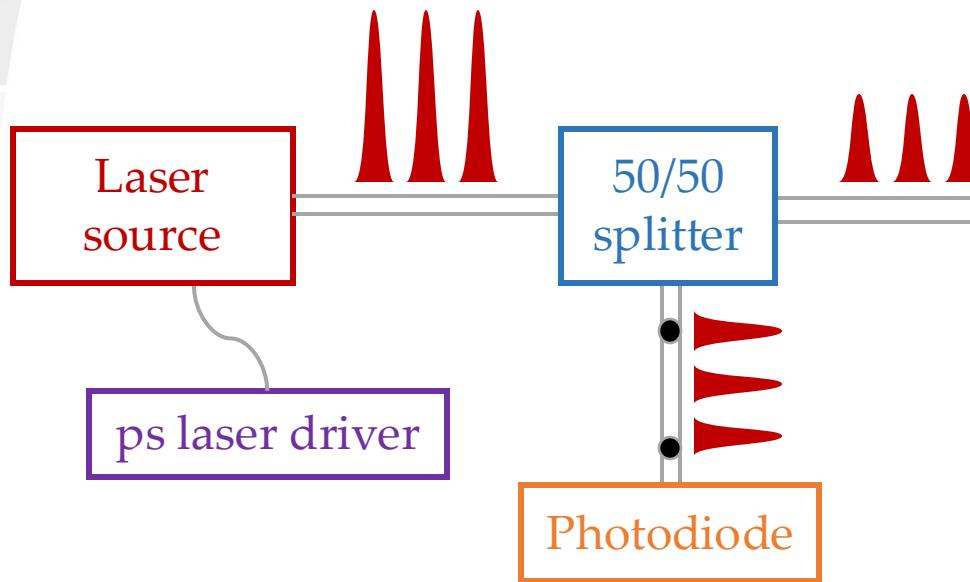
Absorption coefficient: 0.97 0.83



# Recent developments

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- Measuring detection efficiency:



$\Gamma$  = optical path attenuation

$\rho$  = BS ratio

$\eta$  = free air-fiber reflectivity

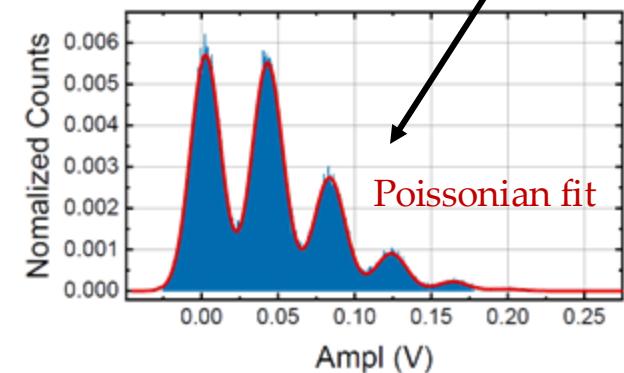
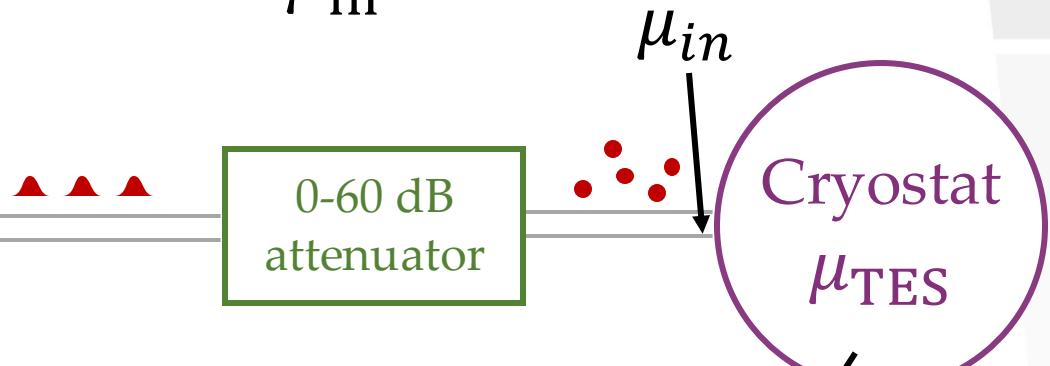
$v$  = laser repetition rate

$\lambda$  = laser wavelength

$hc$  = Plank constant  $\times$  speed of light

$$\mu_{in} = \frac{P_{diode} \cdot \rho \cdot \Gamma}{(1 - \eta) \cdot v} \cdot \frac{\lambda}{hc}$$

$$SDE = \frac{\mu_{TES}}{\mu_{in}}$$

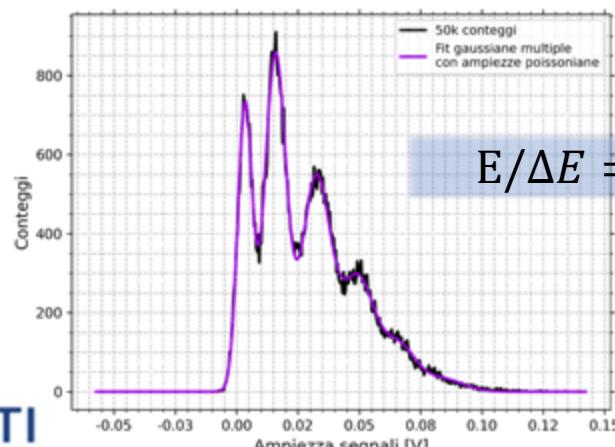


# Preliminary results

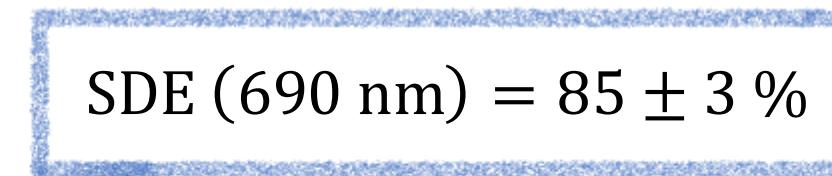
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60 × 60  $\mu\text{m}^2$  TiAuTi TES + AR

Variable [unit]	Value	Uncertainty	Contribution
Wavelength $\lambda$ [m]	6.90e-07	5e-09	0.006145 
Repetition rate $\nu$ [Hz]	3.125e+04	-	-
Free air/fibre interface $\eta$	3.7e-02	-	-
BS ratio $\lambda$	2.30e-03	1e-05	0.004667 
Optical path attenuation $\Gamma$	3.70e-04	5e-06	0.012120 
Photodiode power $P$ [W]	1.98e-08	5e-10	0.022935 
$\mu_{\text{TES}}$ [from Poissonian fit]	1.65e+00	1e-02	0.005670 



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SDE (690 nm) = 85 ± 3 %

# Future steps



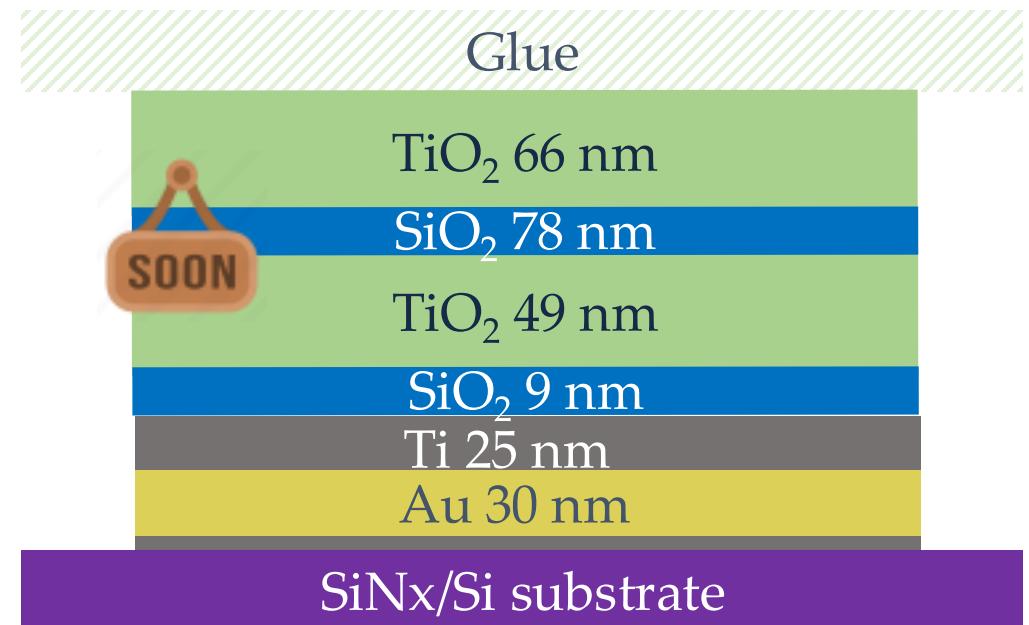
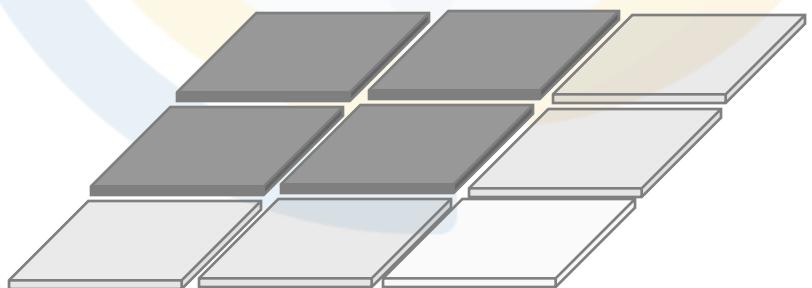
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- Reduce TES response time of about 20%
- Enhance detection efficiency to reach 90%



New 4-oxide AR coating  
Simulations show SDE > 90%

- Fabricate a prototype array of TESs



Thanks for your attention

# Cryogenic setup

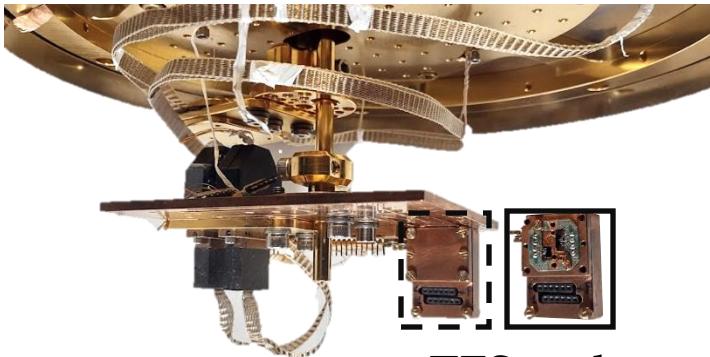
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- Low-temperature setup: pulse-tube cryocooler + ADR

3 K

< 100 mK

- Stages at different temperatures (60 K, 3 K, 500 mK, 30 mK)



TES and  
SQUID box

- ❖ An optical fibre is aligned to the TES active area and glued

